

www.vishay.com

Vishay Semiconductors

Small Signal Fast Switching Diode



FEATURES

- Silicon epitaxial planar diode
- Electrical data identical with the device 1N4154
- QuadroMELF package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS

APPLICATIONS • Extreme fast switches

ADDITIONAL RESOURCES



MECHANICAL DATA

Case: QuadroMELF (SOD-80)

Weight: approx. 34 mg
Cathode band color: black
Packaging codes / options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

PARTS 1	RTS TABLE				
PART	PART ORDERING CODE		CIRCUIT CONFIGURATION	REMARKS	
LS4154	LS4154GS18 or LS4154GS08	-	Single	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V _{RRM}	35	V		
Reverse voltage		V _R	25	V		
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	А		
Repetitive peak forward current		I _{FRM}	500	mA		
Forward continuous current		I _F	300	mA		
Average forward current	V _R = 0	I _{F(AV)}	150	mA		
Power dissipation		P _{tot}	500	mW		

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W	
Junction temperature		Tj	175	°C	
Storage temperature range		T _{stg}	-65 to +175	°C	



www.vishay.com

Vishay Semiconductors

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 30 mA	V _F			1	V
Davaraa valtaaa	V _R = 25 V	I _R			100	nA
Reverse voltage	V _R = 25 V, T _j = 150 °C	I _R			100	μΑ
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V _(BR)	35			V
Diode capacitance	$V_R = 0$, $f = 1$ MHz, $V_{HF} = 50$ mV	C _D			4	pF
	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA}$	t _{rr}			4	ns
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \times I_R, R_L = 100 \Omega$	t _{rr}			2	ns

TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

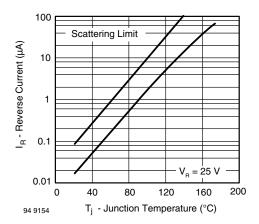


Fig. 1 - Reverse Current vs. Junction Temperature

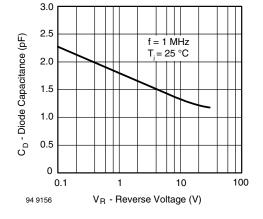


Fig. 3 - Diode Capacitance vs. Reverse Voltage

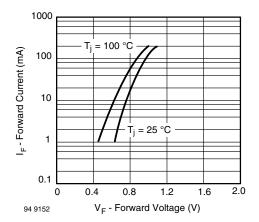


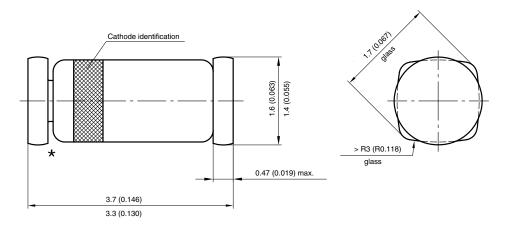
Fig. 2 - Forward Current vs. Forward Voltage



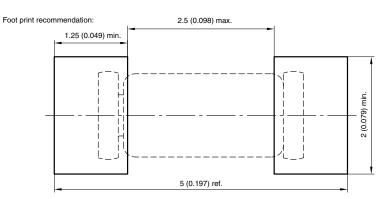
www.vishay.com

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters (inches): QuadroMELF (SOD-80)



★ The gap between plug and glass can be either on cathode or anode side



Created - Date: 03.November.2003 Rev. 11 - Date: 07.June 2006 Document no.:6.560-5006.01-4 96 12071



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

RD0306T-H BAV17-TR BAV19-TR 1N3611 NTE156A NTE525 NTE571 NTE5804 NTE5806 NTE6244 1SS181-TP 1SS193,LF

1SS400CST2RA SDAA13 SHN2D02FUTW1T1G LS4151GS08 1N4449 1N456A 1N4934-E3/73 1N914B 1N914BTR RFUH20TB3S

BAS 28 E6327 BAV199-TP BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 LL4151-GS18 053684A

SMMSD4148T3G 707803H NSVDAN222T1G SP000010217 CDSZC01100-HF BAV199E6433HTMA1 BAV70M3T5G SMBT2001T1G

NTE5801 NTE5800 NTE5808 NTE6240 NTE6248 DLM10C-AT1 BAS28-7 BAW56HDW-13 BAS28 TR VS-HFA04SD60STR-M3

NSVM1MA152WKT1G